

ZHCS750

SURFACE MOUNT SCHOTTKY BARRIER DIODE

Product Summary

- V_R = 40V
- I_F = 750mA
- I_R = 50μA

Description and Applications

- DC DC Converters
- Mobile Telecomms
- PCMIA

Features and Benefits

- High current capability (I_F = 750mA)
- Low V
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Weight: 0.0089 grams (approximate)

SOT23



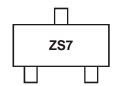
Top View

Ordering Information (Note 1)

Device	Packaging	Shipping	
ZHCS750TA	SOT23	3000/Tape & Reel	

Notes: 1. For Packaging Details, go to our website at http://www.diodes.com.

Marking Information



ZS7 = Product Type Marking Code



Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Units
Continuous Reverse Voltage		V _R	40	V
Continuous Forward Current		I _F	750	mA
Forward Voltage @ I _F = 750mA		V _F	490	mV
Average Peak Forward Current; D.C. = 50%		I _{FAV}	1500	mA
Non Repetitive Forward Current	t ≤ 100μs		12	Α
Non Repetitive Forward Current	t ≤ 10ms	IFSM	5.2	Α

Thermal Characteristics

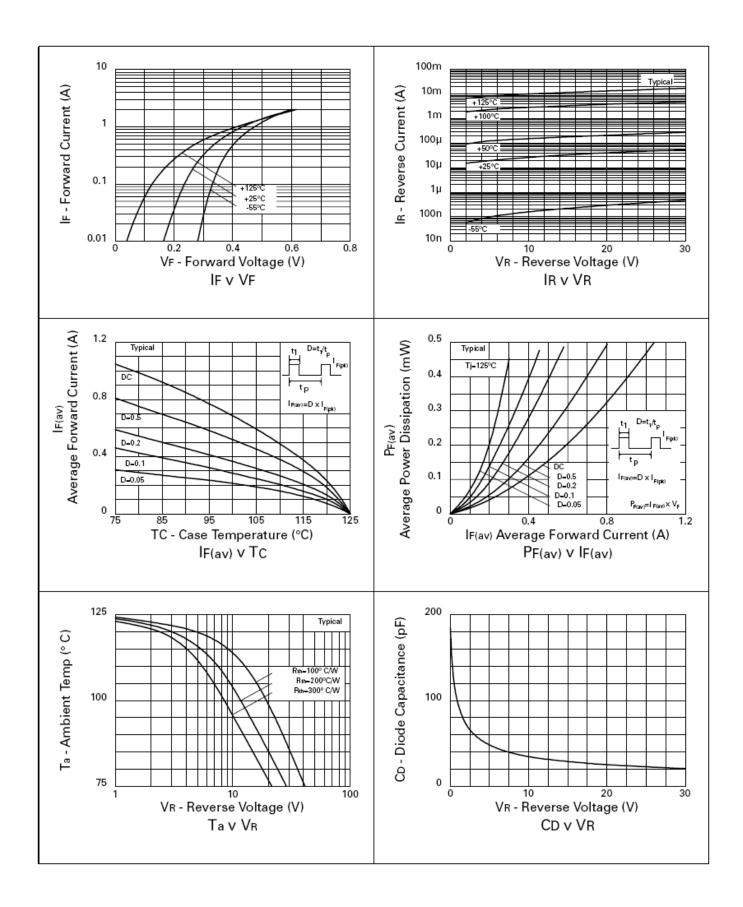
Characteristic	Symbol	Value	Unit
Power Dissipation, T _A = 25°C	P _D	500	mW
Junction Temperature	T_J	125	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

Electrical Characteristics @TA = 25°C unless otherwise specified

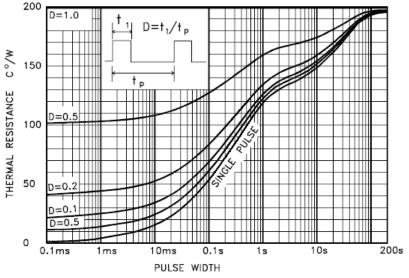
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage	$V_{(BR)R}$	40	60	1	V	$I_R = 300 \mu A$
		-	225	280		$I_F = 50mA$
		-	235	310		$I_F = 100 \text{mA}$
		-	290	350		I _F = 250mA
Forward Voltage (Note 2)	V _F	-	340	420		$I_F = 500 \text{mA}$
		-	390	490		I _F = 750mA
		-	440	540		I _F = 1A
		-	530	650		I _F = 1.5A
Reverse Current	I _R	-	50	100	μА	$V_R = 30V$
Diode Capacitance	C_D	-	25	-	pF	$f = 1MHz$, $V_R = 25V$
Reverse Recovery Time	trr	-	12	1	ns	Switched from I_F = 500mA to I_R = 500mA Measured @ I_R = 50mA

Notes: 2. Measured under pulsed conditions. Pulse width = 300µS. Duty cycle ≤ 2%.



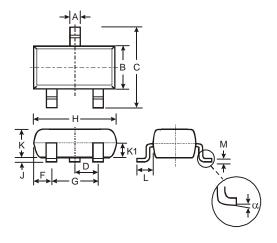






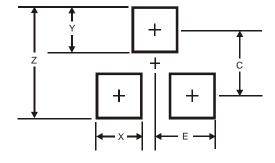
MAXIMUM TRANSIENT THERMAL RESISTANCE*

Package Outline Dimensions



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
C	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Η	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.903	1.10	1.00		
K1	-	-	0.400		
L	0.45	0.61	0.55		
М	0.085	0.18	0.11		
α	0°	8°	-		
All Dimensions in mm					

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Υ	0.9
С	2.0
E	1.35

^{*} Reference above figure, devices were mounted on a 15mmx15mm ceramic substrate.

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